


APPLICATION DATA SHEET

Electronic Version v14

Stylesheet Version v14.0

Title of Invention	FLASH MEMORY CELL AND FABRICATING METHOD THEREOF		
Application Type : regular, utility Attorney Docket Number : 11041-US-PA-1			
Correspondence address: Customer Number: 31561 			
Continuing Data: This is a Division of US application number 10/604,861, filed 2003-08-22 , now pending.			
Inventors Information: <u>Inventor 1:</u> Applicant Authority Type: Inventor Citizenship: TW Name prefix: Mr. Given Name: Ko-Hsing Family Name: Chang Residence: City of Residence: Hsinchu Country of Residence: TW Address-1 of Mailing Address: 12F-1, No. 88, Ta-Hsueh Rd. Address-2 of Mailing Address: City of Mailing Address: Hsinchu State of Mailing Address: Postal Code of Mailing Address: Country of Mailing Address: TW Phone: Fax: E-mail: <u>Inventor 2:</u> Applicant Authority Type: Inventor			

Citizenship:	TW
Name prefix:	Mr.
Given Name:	Hann-Jye
Family Name:	Hsu
Residence:	
City of Residence:	Taichung Hsien
Country of Residence:	TW
Address-1 of Mailing Address:	No. 1, Alley 2, Ling-men Lane, Mei-shan Rd.
Address-2 of Mailing Address:	Mei-shan Tsun, Houli Chen
City of Mailing Address:	Taichung Hsien
State of Mailing Address:	
Postal Code of Mailing Address:	
Country of Mailing Address:	TW
Phone:	
Fax:	
E-mail:	

Attorney Information:

practitioner(s) at Customer Number:

31561



as our attorney(s) or agent(s) to prosecute the application identified above, and to transact all business in the United States Patent and Trademark Office connected therewith.